NE5533/5533A-N,F • NE/SE5534/5534A-N,FE NE5534-D

#### DESCRIPTION

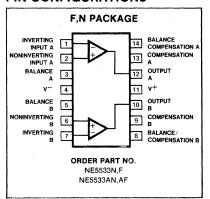
The 5533/5534 are dual and single highperformance low noise operational amplifiers. Compared to other operational amplifiers, such as TL083, they show better noise performance, improved output drive capability and considerably higher small-signal and power bandwidths.

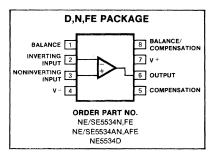
This makes the devices especially suitable for application in high quality and professional audio equipment, in instrumentation and control circuits and telephone channel amplifiers. The op amps are internally compensated for gain equal to, or higher than, three. The frequency response can be optimized with an external compensation capacitor for various applications (unity gain amplifier, capacitive load, slew-rate, low overshoot, etc.) If very low noise is of prime importance, it is recommended that the 5533A/5534A version be used which has guaranteed noise specifications.

#### **FEATURES**

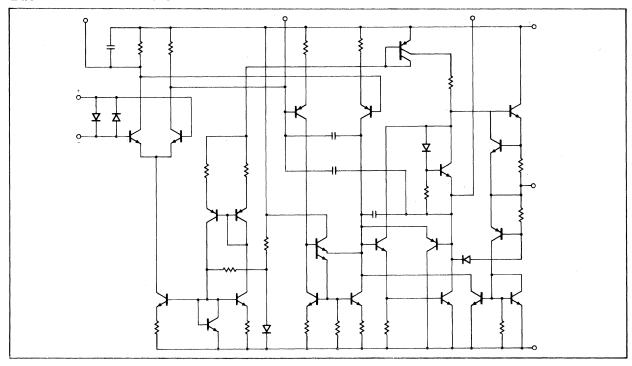
- Small-signal bandwidth: 10MHz
- Output drive capability: 600 $\Omega$ , 10V (rms) at  $V_S = \pm 18V$
- Input noise voltage: 4nV/√Hz
- DC voltage gain: 100000
- AC voltage gain: 6000 at 10kHz
- . Power bandwidth: 200kHz
- Slew-rate: 13V/μs
- Large supply voltage range: ±3 to ±20V

#### **PIN CONFIGURATIONS**





#### **EQUIVALENT SCHEMATIC**



# SINGLE AND DUAL LOW NOISE OPERATIONAL AMPLIFIER

NE5533/5533A NE/SE5534/5534A

NE5533/5533A-N,F • NE/SE5534/5534A-N,FE NE5534-D

#### **ABSOLUTE MAXIMUM RATINGS**

	PARAMETER		UNIT
Vs Vin Vdiff Ta	Supply voltage Input voltage Differential input voltage <sup>1</sup> Operating temperature range	±22 ±V supply ±.5	V V
T <sub>STG</sub> TJ	SE 5534/5534A NE5533/5533A/5534/5534A Storage temperature Junction temperature	-55 to +125 0 to +70 -65 to +150 150	°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°
PD	Power dissipation at 25° C <sup>2</sup> 5533N, 5534N, 5534FE 5533F Output short circuit duration <sup>3</sup> Lead temperature (soldering 10 sec)	800 1000 indefinite 300	mW mW

#### NOTES

- 1. Diodes protect the inputs against over-voltage. Therefore, unless current-limiting resistors are used, large currents will flow if the differential input voltage exceeds 0.6V. Maximum current should be limited to  $\pm 10$ mA.
- 2. For operation at elevated temperature, derate packages based on the following junction-to-ambient thermal resistances:
- 8-pin ceramic (FE) 140° C/W 14-pin ceramic (F) 110°C/W 8-pin plastic (N) 162° C/W 14-pin plastic (N) 150° C/W
- 3. Output may be shorted to ground at  $V_S = \pm 15V$ ,  $T_A = 25^{\circ}C$ . Temperature and/or supply voltages must be limited to ensure dissipation rating is not exceeded.

## DC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$ , $V_S = \pm 15V$ unless otherwise specified.1.2

PARAMETER		TEST CONDITIONS	SE5534/5534A			NE5533/5533A 5534/5534A			UNIT
			Min	Тур	Max	Min	Тур	Max	0
Vos	Offset voltage	Over temperature		.5	2 3		.5	4 5	mV mV
los	Offset current	Over temperature		10	200 500		20	300 400	nA nA
lΒ	Input current	Over temperature		400	800 1500		500	1500 2000	nA nA
lcc	Supply current Per op amp	Over temperature		4	6.5 9		4	8	mA mA
V <sub>CM</sub> CMRR PSRR	Common mode input range Common mode rejection ratio Power supply rejection ratio		±12 80	±13 100 10	50	±12 70	±13 100 10	100	V dB μV/V
Avol	Large signal voltage gain	$R_L \ge 600\Omega$ , $V_O = \pm 10V$ Over temperature	50 25	100		25 15	100		V/mV V/mV
Vout	Output swing	$\begin{array}{c} R_L \geq 600\Omega \\ R_L \geq 600\Omega \ V_S = \pm 18V \end{array}$	±12 ±15	±13 ±16		±12 ±15	±13 ±16		V V
R <sub>IN</sub> I <sub>SC</sub>	Input resistance Output short circuit current		50	100 38		30	100 38		kΩ mA

#### NOTES

- 1. For NE5533/5533A/5534/5534A, T<sub>MIN</sub> = 0 °C, T<sub>MAX</sub> = 70 °C 
  2. For SE5534/5534A, T<sub>MIN</sub> = -55 °C, T<sub>MAX</sub> = +125 °C

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## AC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$ , $V_S = \pm 15V$ unless otherwise specified.

PARAMETER		TEST CONDITIONS	SE5534/5534A			NE5533/5533A 5534/5534A			UNIT
			Min	Тур	Max	Min	Тур	Max	
Rout	Output resistance	$A_V = 30$ dB closed loop $f = 10$ kHz, $R_L = 600\Omega$ , $C_C = 22$ pF		0.3			0.3		Ω
Transient response		Voltage follower, $V_{IN} = 50 \text{mV}$ $R_L = 600\Omega$ , $C_C = 22 \text{pF}$ , $C_L = 100 \text{pF}$			;				
TR	Rise time Overshoot			20 20			20 20		ns %
Transient response		$V_{IN} = 50 \text{mv}, R_L = 600 \Omega$ $C_C = 47 \text{pF}, C_L = 500 \text{pF}$							
TR	Rise time Overshoot			50 35			50 35		ns %
AC	Gain	$f = 10kHz, C_C = 0$ $f = 10kHz, C_C = 22pF$		6 2.2			6 2.2		V/mV V/mV
	Gain bandwidth product	C <sub>C</sub> = 22pF, C <sub>L</sub> = 100pF		10			10		mHz
	Slew rate	$C_C = 0$ $C_C = 22pF$		13 6			13 6		V/μS V/μS
	Power bandwidth	$V_{OUT} = \pm 10V, C_C = 0$ $V_{OUT} = \pm 10V, C_C = 22pF$ $V_{OUT} = \pm 14V, R_L = 600\Omega$ $C_C = 22pF, V_{CC} = \pm 18V$		200 95 70			200 95 70		kHz kHz kHz

## **ELECTRICAL CHARACTERISTICS** $T_A = 25^{\circ}C$ , $V_S = \pm 15V$ unless otherwise specified.

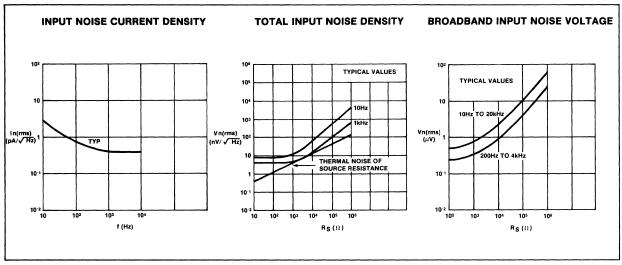
	TEST CONDITIONS	5533/5534			5533A/5534A			
PARAMETER		Min	Тур	Max	Min	Тур	Max	UNIT
Input noise voltage	f <sub>O</sub> = 30Hz f <sub>O</sub> = 1kHz		7 4			5.5 3.5	7 4.5	nV/√Hz nV/√Hz
Input noise current	f <sub>O</sub> = 30Hz f <sub>O</sub> = 1kHz		2.5 0.6			1.5 0.4		pA/√Hz pA/√Hz
Broadband noise figure	$f = 10Hz - 20kHz, R_S = 5k\Omega$					0.9		dB
Channel separation	$f = 1kHz, R_S = 5k\Omega$		110			110		dB

# SINGLE AND DUAL LOW NOISE OPERATIONAL AMPLIFIER

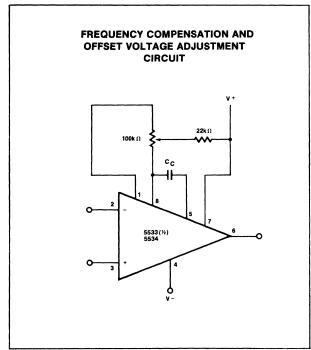
NE5533/5533A NE/SE5534/5534A

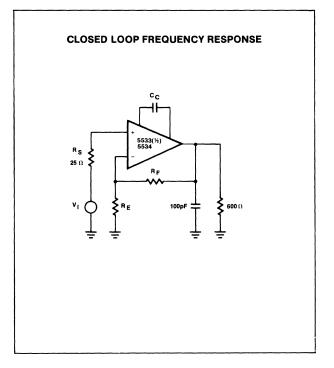
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### TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)



## **TEST LOAD CIRCUITS**





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### TYPICAL PERFORMANCE CHARACTERISTICS

